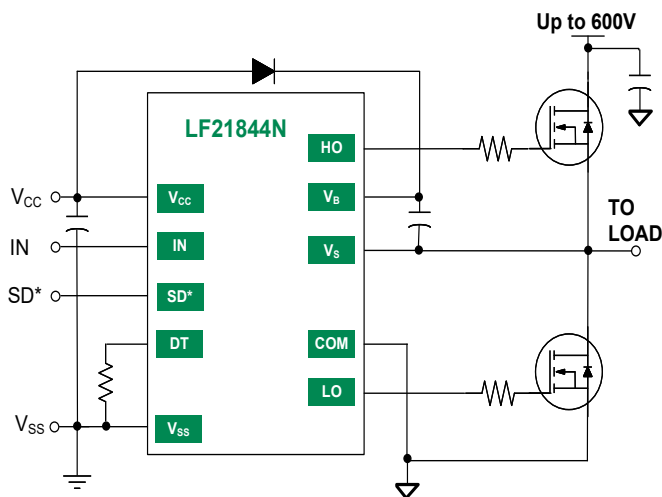# LF21844N

Half-Bridge Gate Driver

Features

- ■ Floating high-side driver in bootstrap operation to 600V
- ■ Drives two N-channel MOSFETs or IGBTs in a half-bridge configuration
- ■ 1.4A source / 1.7A sink output current capability
- ■ Outputs tolerant to negative transients
- ■ Programmable dead time to protect MOSFETs
- ■ Wide low-side gate driver supply voltage: 10V to 20V
- ■ Wide logic supply voltage offset voltage: -5V to 5V
- ■ Logic input (IN and SD*) 3.3V capability
- ■ Schmitt triggered logic inputs with internal pull up and pull down
- ■ Under Voltage Lockout (UVLO) for high-side and low side drivers
- ■ Extended temperature range:-40ºC to +125ºC

Applications

- ■ DC-DC Converters
- ■ AC-DC Inverters
- ■ Motor Controls
- ■ Class D Power Amplifiers

Typical Application
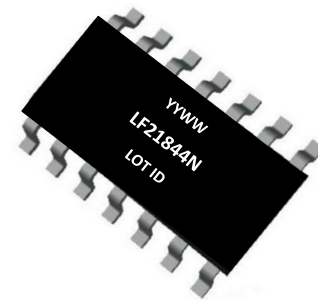

Description

LF21844N is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. The high voltage technology enables the LF21844N's high side to switch to 600V in a bootstrap operation.

The LF21844N logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction. Programmable dead time, by an external resistor, provides more system level flexibility.

The LF21844N is offered in SOIC(N)-14 package. It operates over the extended temperature range of -40 °C to +125 °C .
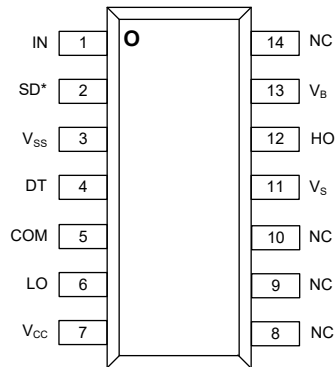

SOIC(N)-14

Ordering Information

Year Year Week Week

Part #	Package	Pack / Qty	Mark
LF21844NTR	SOIC(N)-14	T&R / 2500	YYWW LF21844N Lot ID

LF21844N
Half-Bridge Gate Driver

1 Specifications

1.1 Pin Diagrams

Top View: SOIC(N)-14
LF21844N

1.2 Pin Descriptions

Pin #	Pin Name	Pin Type	Description
1	IN	Input	Logic input for high-side and low-side gate driver outputs (HO and LO), in phase with HO
2	SD*	Input	Logic input for shutdown, active low.
3	V_{SS}	Power	Logic ground
4	DT	Output	Programmable deadtime lead
5	COM	Power	Low-side return
6	LO	Output	Low-side gate drive output
7	V_{CC}	Power	Low-side and logic fixed supply
11	V_S	Power	High-side floating supply return
12	HO	Output	High-side gate drive output
13	V_B	Power	High-side floating supply
8, 9, 10, 14	NC	No Connect	Not connected internally

1.3 Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
High side floating supply voltage	V_B	-0.3	+624	V
High side floating supply offset voltage	V_S	V_B-24	V_B+0.3	V
High side floating output voltage	V_{HO}	V_S-0.3	V_B+0.3	V
Offset supply voltage transient	dV_S/dt	--	50	V/ns
Programmable dead time voltage	V_{DT}	V_{SS}-0.3	V_{CC}+0.3	V
Low side fixed supply voltage	V_{CC}	-0.3	+24	V
Low side output voltage	V_{LO}	-0.3	V_{CC}+0.3	V
Logic Supply offset voltage	V_{SS}	V_{CC} -24	V_{CC}+0.3	V
Logic input voltage (IN and SD*)	V_{IN}	V_{SS}-0.3	V_{CC}+0.3	V
Package power dissipation	P_D	--	1.0	W
Junction Operating Temperature	T_J	--	+150	℃
Storage Temperature	T_{STG}	-55	+150	℃

Unless otherwise specified all voltages are referenced to COM . All electrical ratings are at T_A= 25 ℃

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

1.4 Thermal Characteristics

Parameter	Symbol	Rating	Unit
Junction to ambient	$\emptyset_{JA}$	120	℃/W

Thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

1.5 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High side floating supply absolute voltage	V_B	$V_S + 10$	$V_S + 20$	V
High side floating supply offset voltage	V_S	*NOTE1*	600	V
High side floating output voltage	V_{HO}	V_S	V_B	V
Logic and Low side fixed supply voltage	V_{CC}	10	20	V
Low side output voltage	V_{LO}	0	V_{CC}	V
Logic input voltage (IN & SD*)	V_{IN}	V_{SS}	5	V
Programmable deadtime voltage	V_{DT}	V_{SS}	*Note2*	V
Logic ground	V_{SS}	-5	+5	V
Ambient temperature	T_A	-40	125	°C

Unless otherwise specified all voltages are referenced to COM

NOTE1 *High-side driver remains operational for V_S transients down to -5V*

NOTE2 *Recommended pull down resistor to V_{SS}: 0 - 200K , minimum 1/8W suggested*

1.6 DC Electrical Characteristics

$V_{CC} = V_{BS} = 15V$, $V_{SS} = V_{COM} = 0V$, and $T_A = 25 °C$, unless otherwise specified.

The V_{IN} and I_{IN} parameters are referenced to V_{SS} and are applicable to both logic input pins: IN and SD*. The V_0 and I_0 parameters are applicable to the respective output pins: HO and LO and are referenced to COM.

Parameter	Symbol	Conditions	MIn	Typ	Max	Unit
Logic "1" input voltage	V_{IH}	$V_{CC} = 10\,V$ to $20\,V$ **NOTE3**	2.5	--	--	V
Logic "0" input voltage	V_{IL}		--	--	0.8	
Logic input voltage hysteresis	$V_{IN(HYS)}$		--	0.3	--	
High level output voltage, $V_{BIAS} - V_O$	V_{OH}	$I_O = 0A$	--	--	1.4	
Low level output voltage, V_O	V_{OL}	$I_O = 20mA$	--	--	0.2	
Offset supply leakage current	I_{LK}	$VB = VS = 600V$	--	--	50	µA
Quiescent V_{BS} supply current	I_{BSQ}	$V_{IN} = 0V$ or $5V$	20	60	150	
Quiescent V_{CC} supply current	I_{CCQ}	$V_{IN} = 0V$ or $5V$	0.4	1.0	1.8	mA
Logic "1" input bias current	I_{IN+}	$V_{IN} = 5V$	--	25	60	µA
	I_{SD+}		--	--	1	
Logic "0" input bias current	I_{IN-}	$V_{IN} = 0V$	--	--	1	
	I_{SD-}		--	25	60	
V_{CC}, V_{BS} UVLO off, positive going threshold	V_{UV+}	--	8	8.9	9.8	V
V_{CC}, V_{BS} UVLO enable, negative going threshold	V_{UV-}	--	7.4	8.2	9	
UVLO hysteresis	$V_{UV(HYS)}$	--	--	0.7	--	
Output high short circuit pulsed current	I_{O+}	$V_O = 0V$, $t \le 10\,µs$	1.4	1.9	--	A
Output low short circuit pulsed current	I_{O-}	$V_O = 15V$, $t \le 10\,µs$	1.7	2.3	--	

NOTE3 *For optimal operation, it is recommended the input pulse to IN should have a minimum amplitude of 2.5V with a minimum pulse width of 2 x t_{DT} (deadtime)*

1.7 AC Electrical Characteristics

$V_{CC}=V_{BS}= 15V$, $V_{SS} = V_{COM}=0V$, $C_L = 1000$ pF, and $T_A = 25$ °C unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-on propagation delay	t_{ON}	$V_S = 0V$	--	680	900	ns
Turn-off propagation delay	t_{OFF}	$V_S = 0$ V or 600V	--	270	400	
Shut-down propagation delay	t_{SD}	--	--	180	270	
Propagation delay matching, HO & LO turn-on	$t_{DM\,ON}$	--	--	--	90	
Propagation delay matching, HO & LO turn-off	$t_{DM\,OFF}$	--	--	--	40	
Turn-on rise time	t_r	$V_S = 0V$	--	40	60	
Turn-off fall time	t_f		--	20	35	
Deadtime	t_{DT}	$R_{DT}=0\Omega$	280	400	520	ns
		$R_{DT}= 200k\Omega$	4	5	6	µs
Deadtime matching	$t_{DT\,MT}$	$R_{DT}=0\Omega$	--	0	50	ns
		$R_{DT}= 200k\Omega$	--	0	600	

2 Functional Description

2.1 Functional Block Diagram
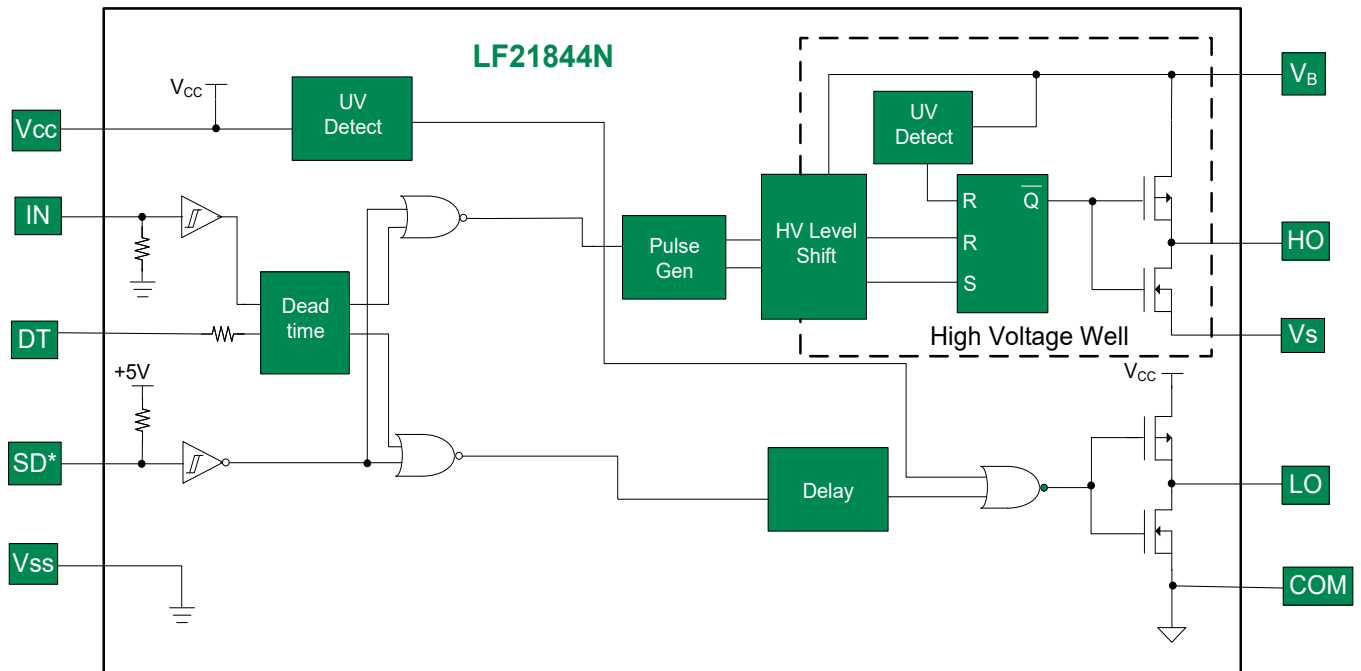
2.2 Timing Waveforms

Figure 1. Input / Output Logic Diagram
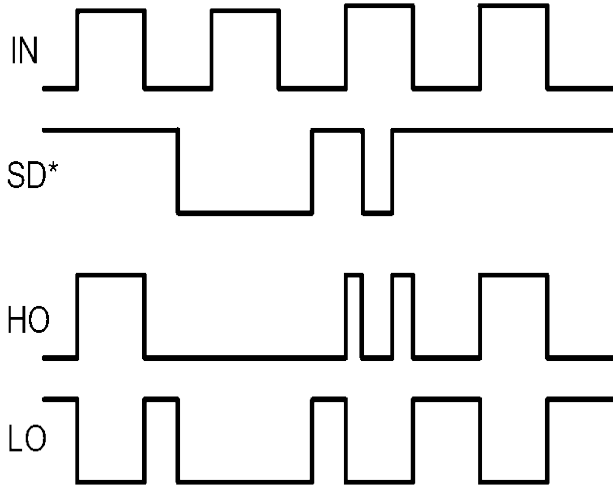
Figure 2. Shutdown Waveform Definitions
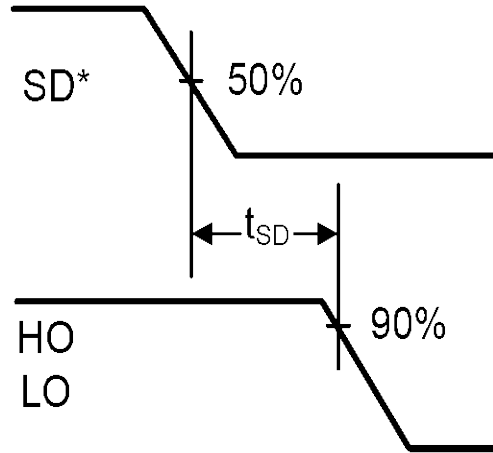
Figure 3. Input-to-Output Delay Timing Diagram
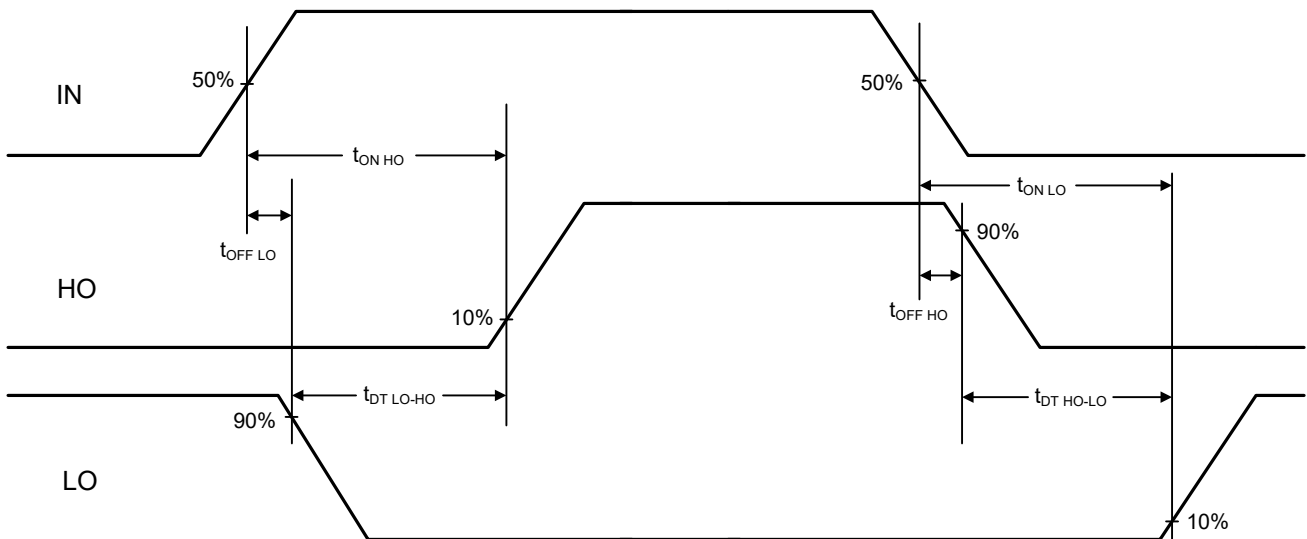
Deadtime $t_{DT\ LO-HO} = t_{ON\ HO} - t_{OFF\ LO}$
$t_{DT\ HO-LO} = t_{ON\ LO} - t_{OFF\ HO}$

Deadtime matching
$t_{MDT} = t_{DT\ LO-HO} - t_{DT\ HO-LO}$

Delay matching
$t_{DM\ OFF} = t_{OFF\ LO} - t_{OFF\ HO}$
$t_{DM\ ON} = t_{ON\ LO} - t_{ON\ HO}$

2.3 Application Information
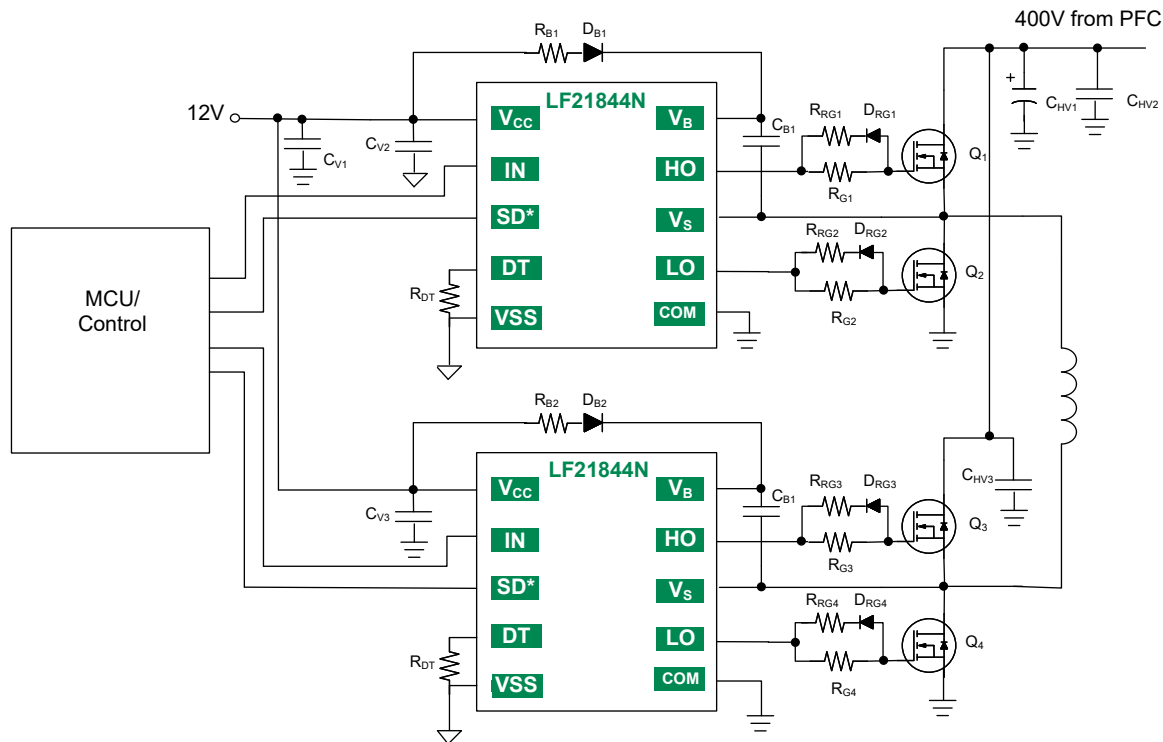
Figure 4. Primary side of Full Bridge converter using LF21844N

■ RRG1, RRG2, RRG3, and RRG4 values are typically between 0Ω and 10Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 10Ω is used in this example.

■ It is **highly recommended** the input pulse to IN should have an amplitude of 2.5V minimum (for V_{CC}=15V) with a minimum pulse width of 2 x t_{DT} (deadtime).

■ RG1, RG2, RG3, and RG4 values are typically between 10Ω and 100Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 50Ω is used in this example.

■ RB1 and RB2 value is typically between 3Ω and 20Ω, exact value depending on bootstrap capacitor value and amount of current limiting required for bootstrap capacitor charging; 10Ω is used in this example. Also DB1 and DB2 should be an ultra fast diode of 1A rating minimum and voltage rating greater than system operating voltage.

3 Performance Data

Unless otherwise noted $V_{CC} = V_{BS} = 15V$, $T_A = 25\ °C$, $V_{COM} = 0V$ and values are typical.

Figure 5. Turn-on Propagation Delay vs. Supply Voltage
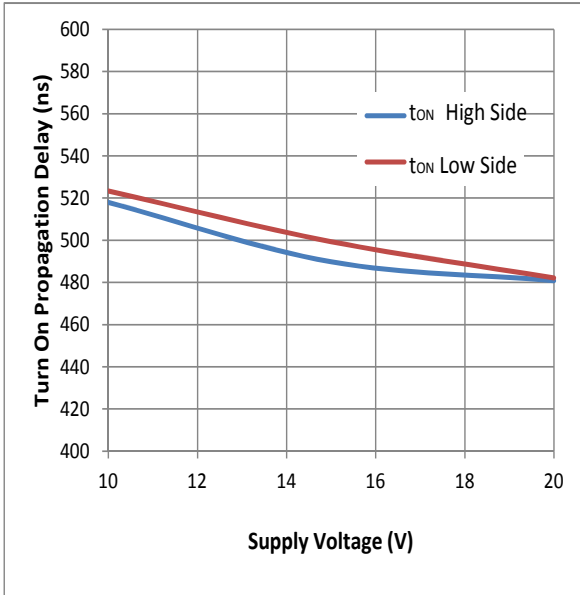
Figure 6. Turn-on Propagation Delay vs. Temperature
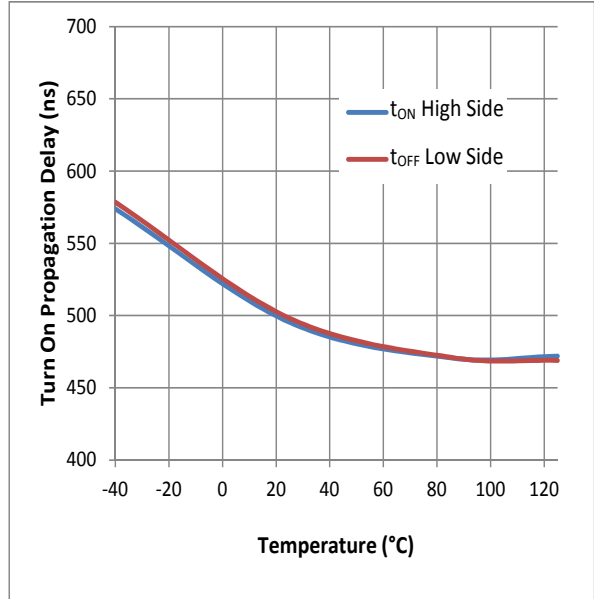
Figure 7. Turn-off Propagation Delay vs. Supply Voltage
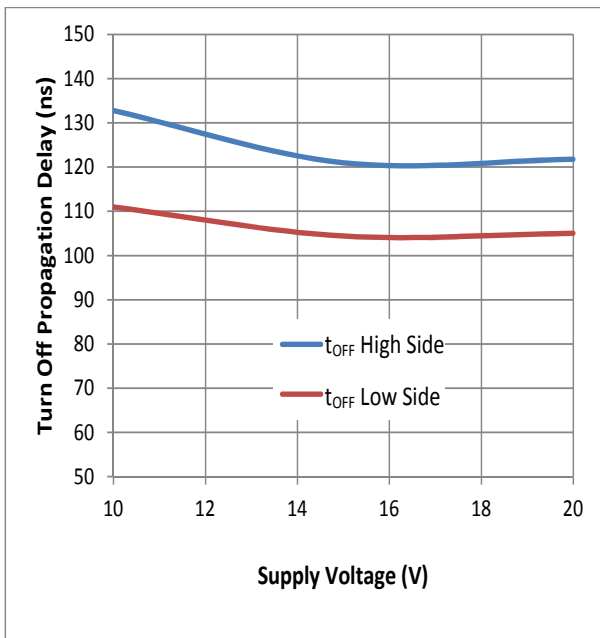
Figure 8. Turn-off Propagation Delay vs. Temperature
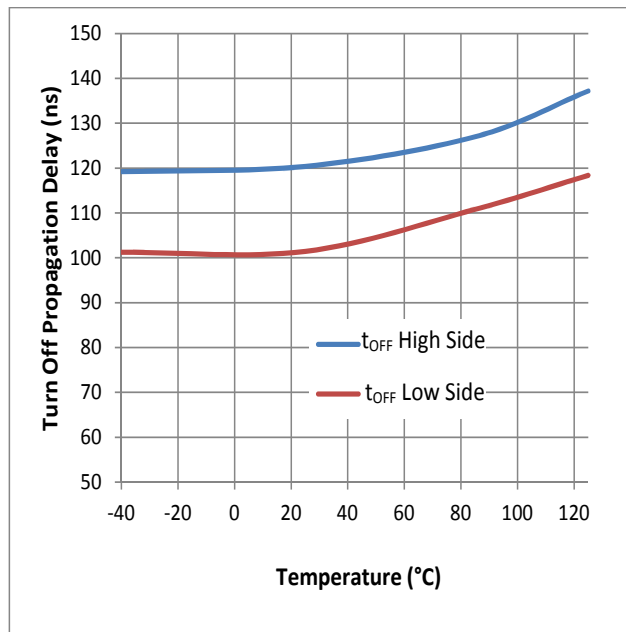
Figure 9. Rise Time vs. Supply Voltage
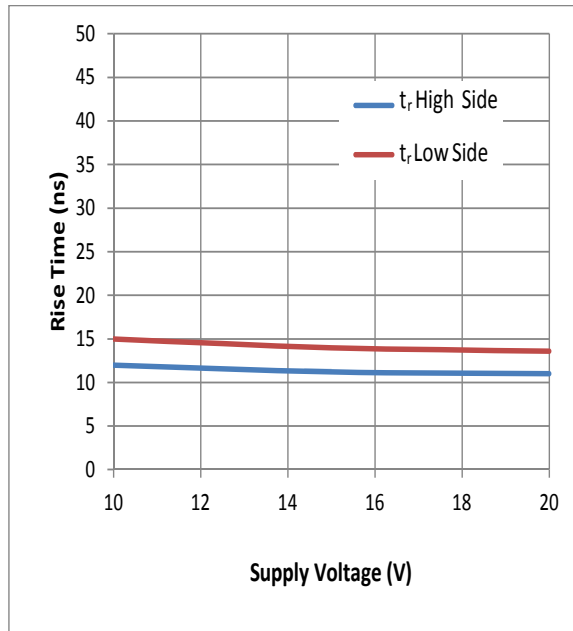
Figure 10. Rise Time vs. Temperature
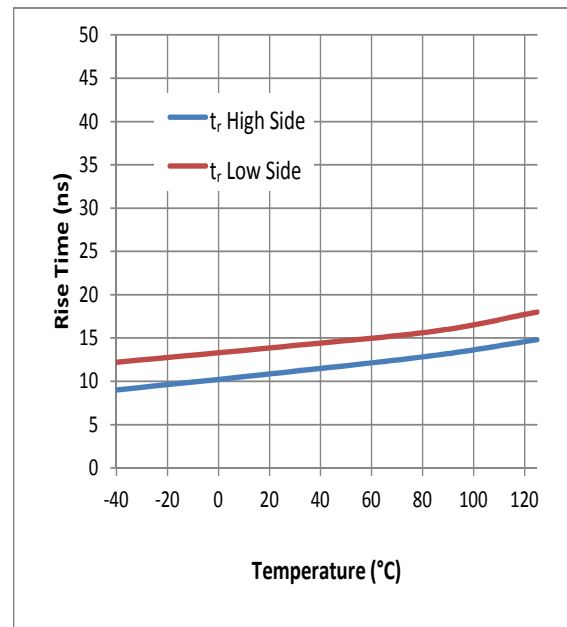
Figure 11. Fall Time vs. Supply Voltage
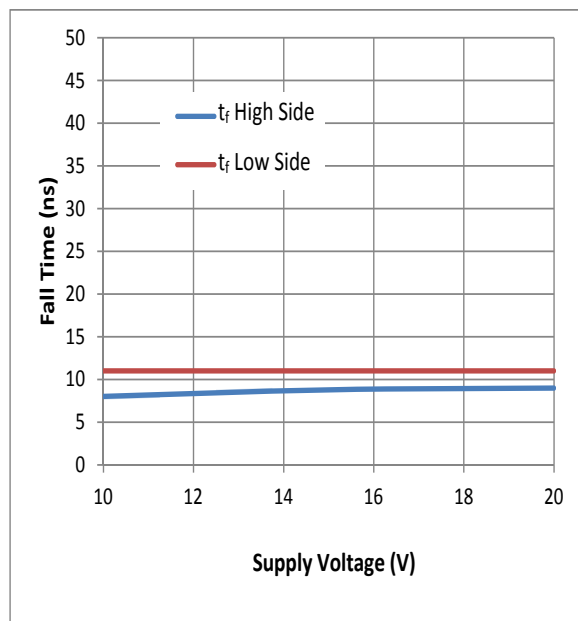
Figure 12. Fall Time vs. Temperature
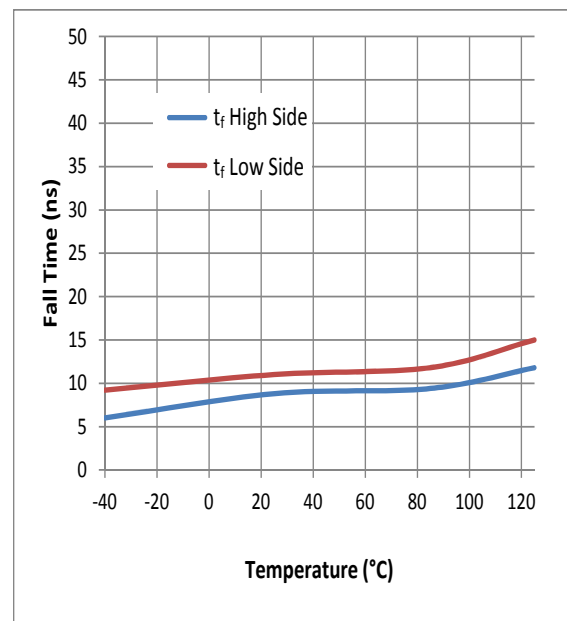
Figure 13. Deadtime vs. Supply Voltage
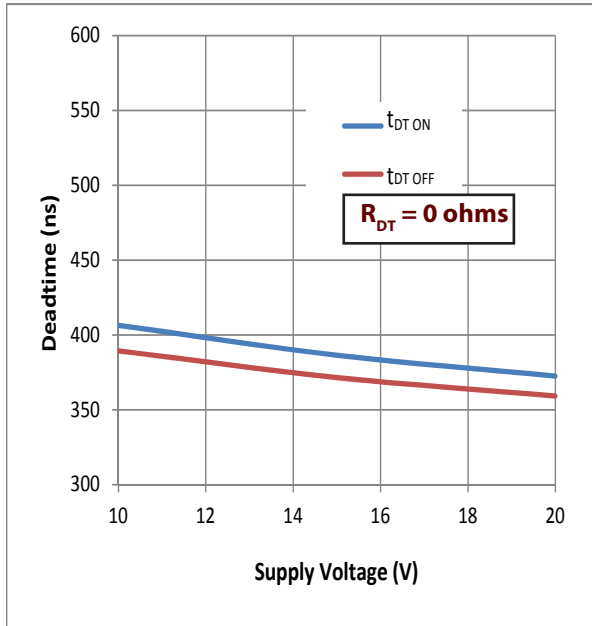
Figure 14. Deadtime vs. Temperature
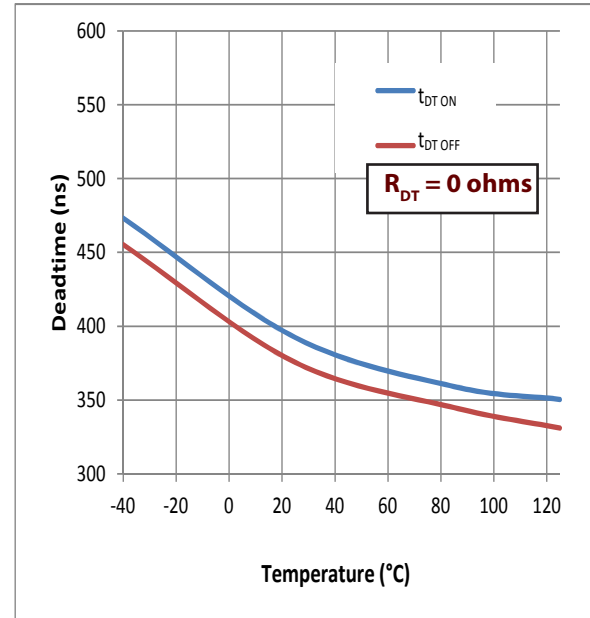
Figure 15. Delay Matching vs. Supply Voltage
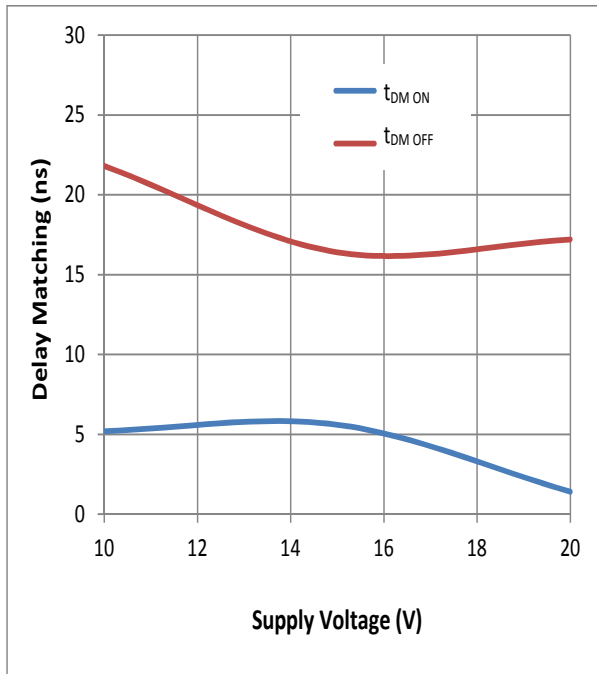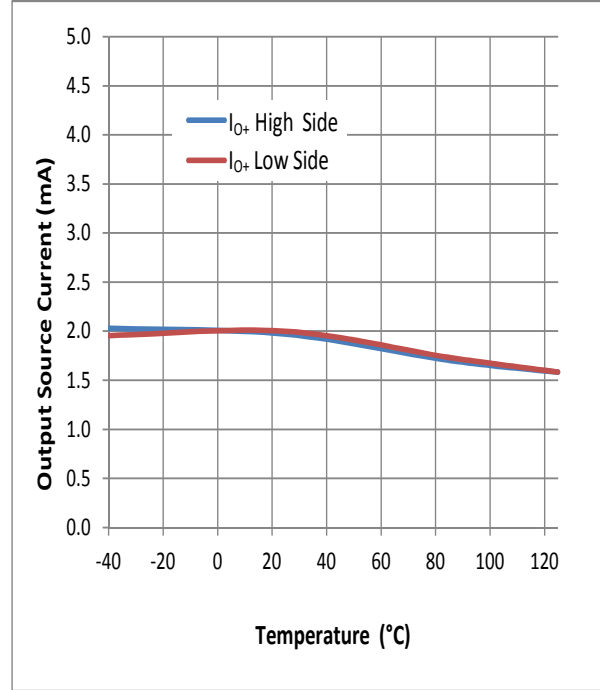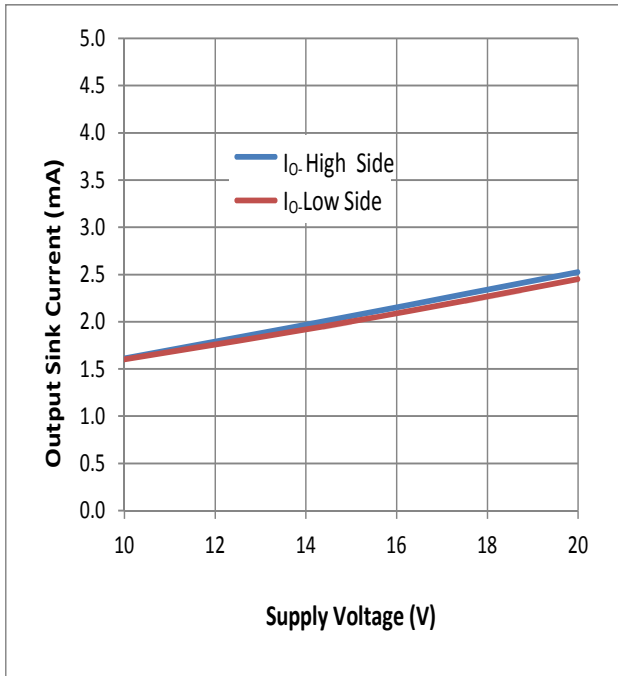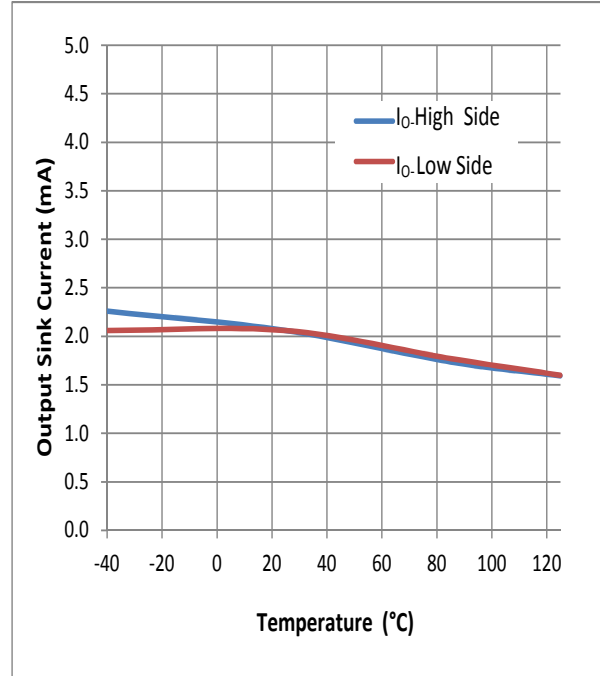

Figure 16. Delay Matching vs. Temperature
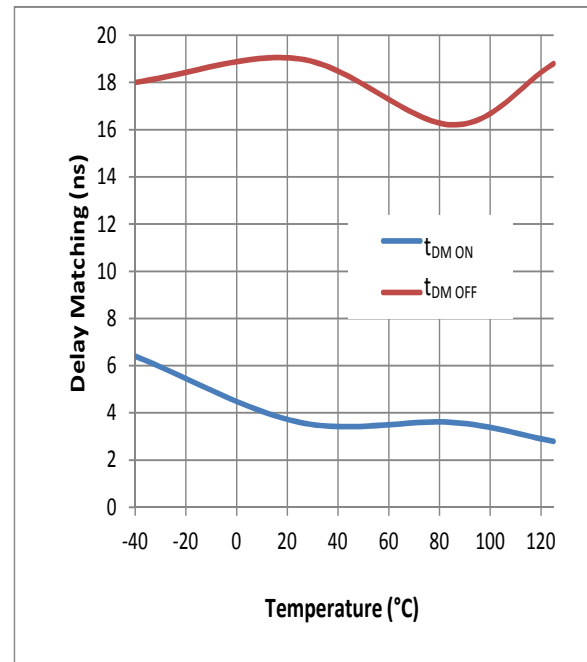
Figure 17. Output Source Current vs. Supply Voltage
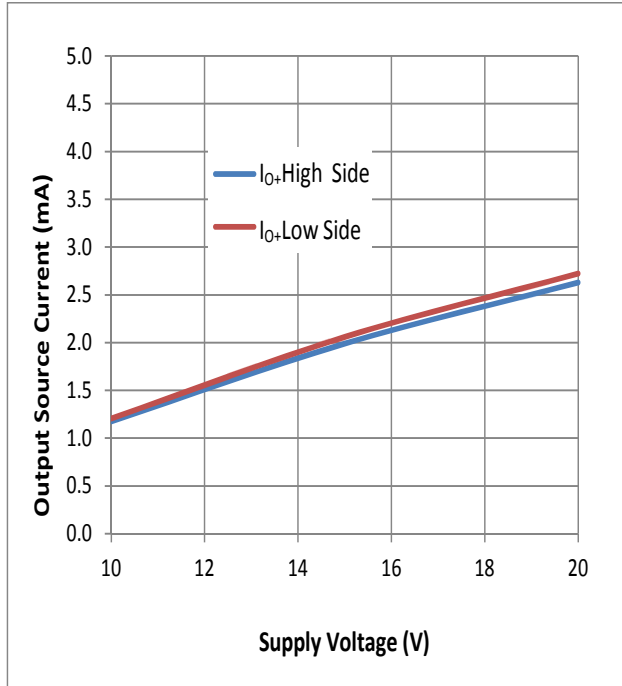
Figure 18. Output Source Current vs. Temperature

Figure 19. Output Sink Current vs. Supply Voltage
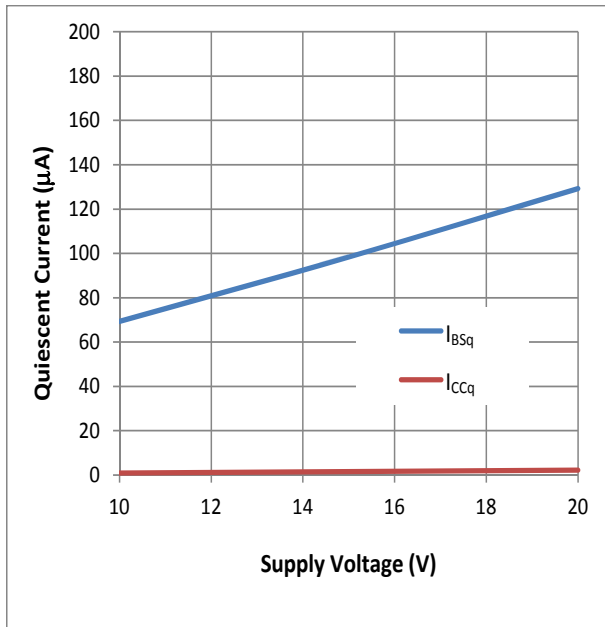

Figure 20. Output Sink Current vs. Temperature
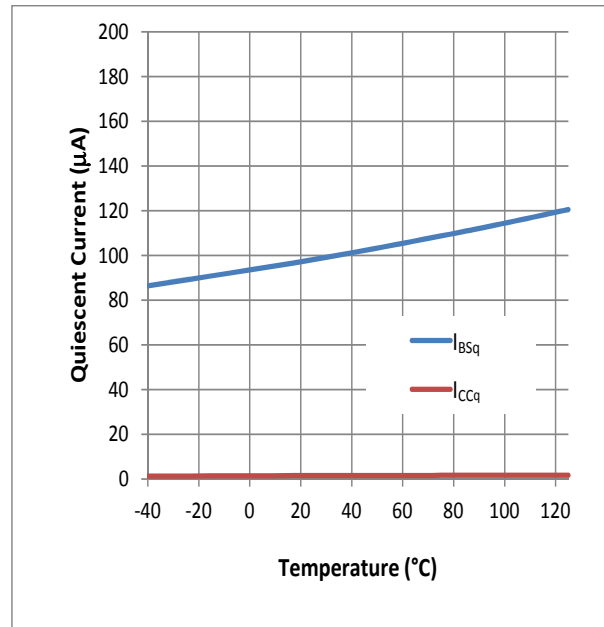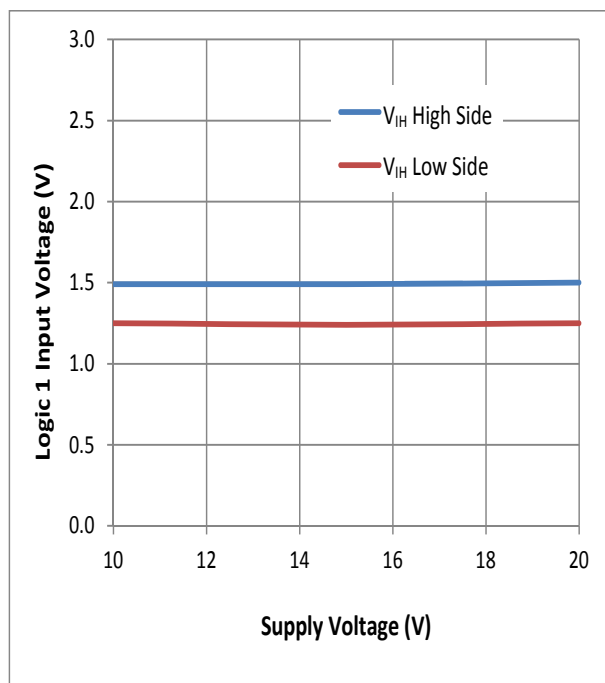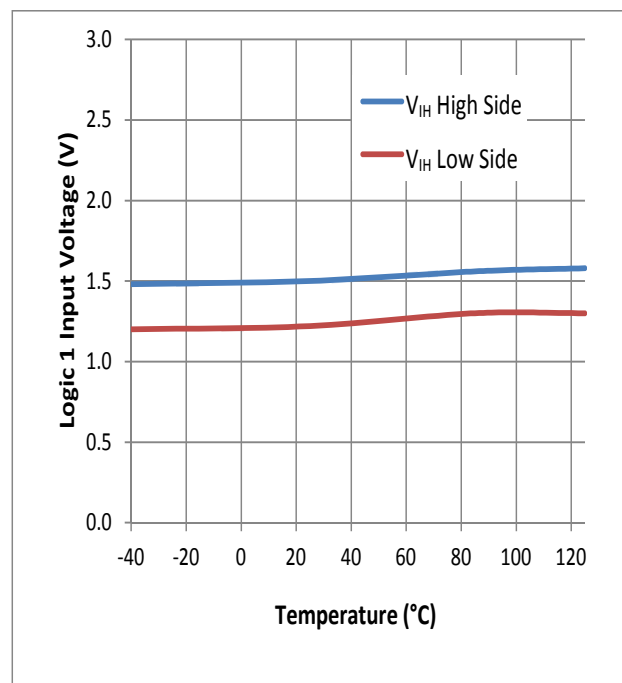
Figure 21. Quiescent Current vs. Supply Voltage

Figure 22. Quiescent Current vs. Temperature

Figure 23. Logic 1 Input Voltage vs. Supply Voltage

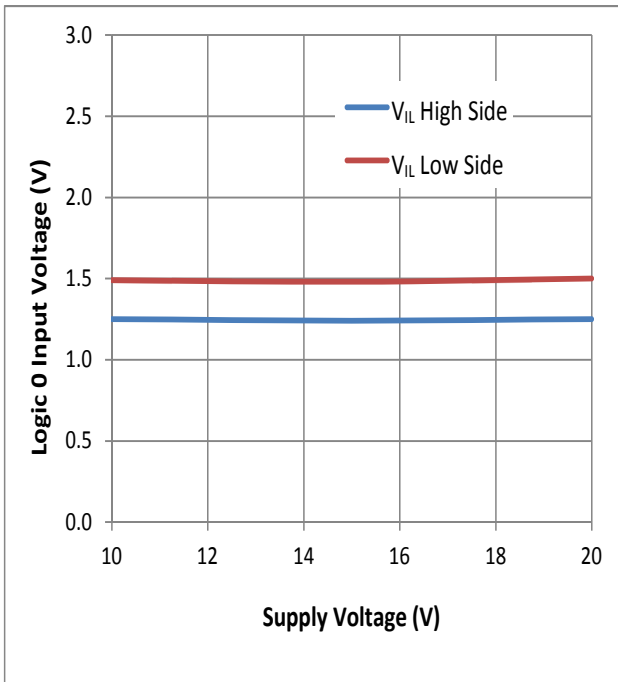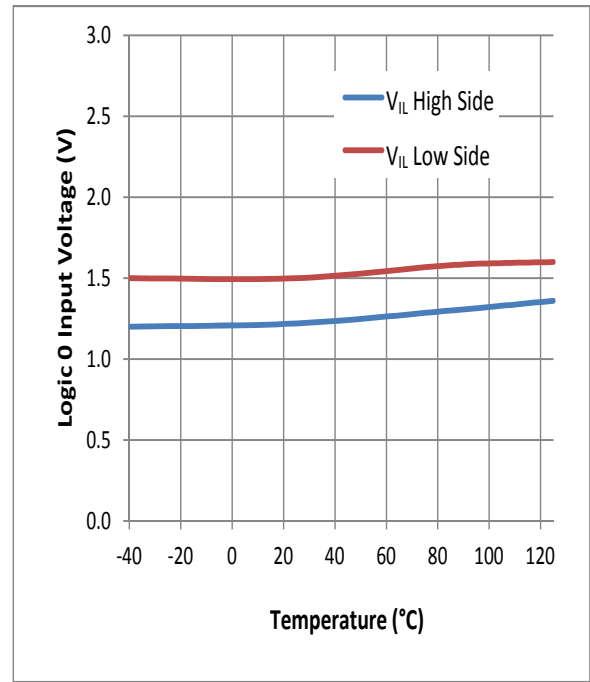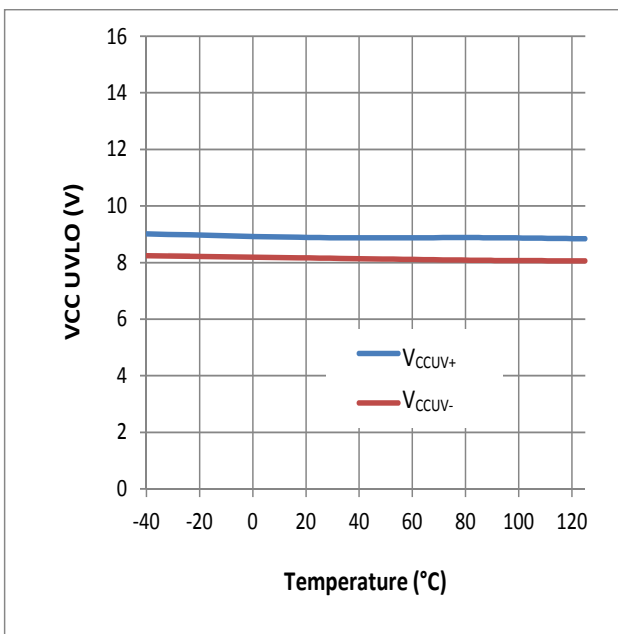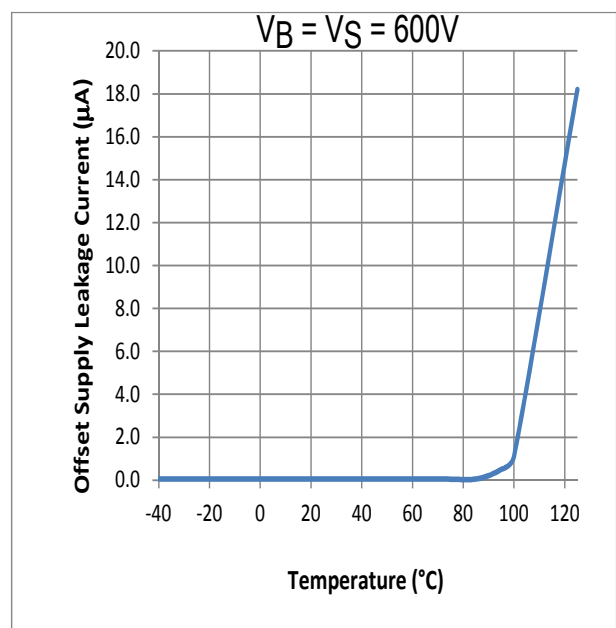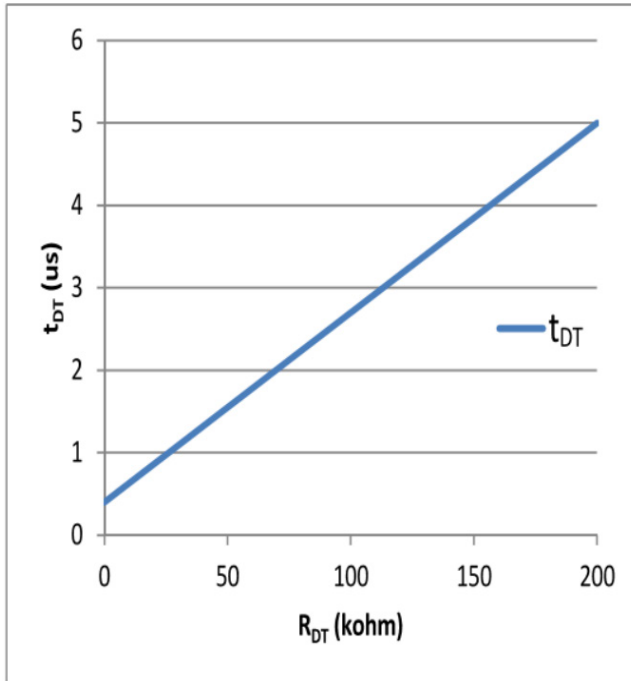**Figure 24.** Logic 1 Input Voltage vs. Temperature

Figure 25. Logic 0 Input Voltage vs. Supply Voltage

Figure 26. Logic 0 Input Voltage vs. Temperature

Figure 27. V_{CC} UVLO vs. Temperature

Figure 28. Offset Supply Leakage Current Temperature

Figure 29. t_{DT} vs R_{DT}

4 Manufacturing Information

4.1 Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. Littelfuse Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** rating as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033.**

Device	Moisture Sensitivity Level (MSL) Classification
LF21844N	MSL3

4.2 ESD Sensitivity

This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

4.3 Reflow Profile

Provided in the table below is the IPC/JEDEC J-STD-020 Classification Temperature (T_C) and the maximum dwell time the body temperature of these surface mount devices may be (T_C - 5)°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

| Device	Classification Temperature(Tc)	Dwell Time (tp)	Max Reflow Cycles
LF21844N	260°C	30 seconds	3

4.4 Board Wash

Littelfuse recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

5 Package Dimensions: SOIC(N)-14
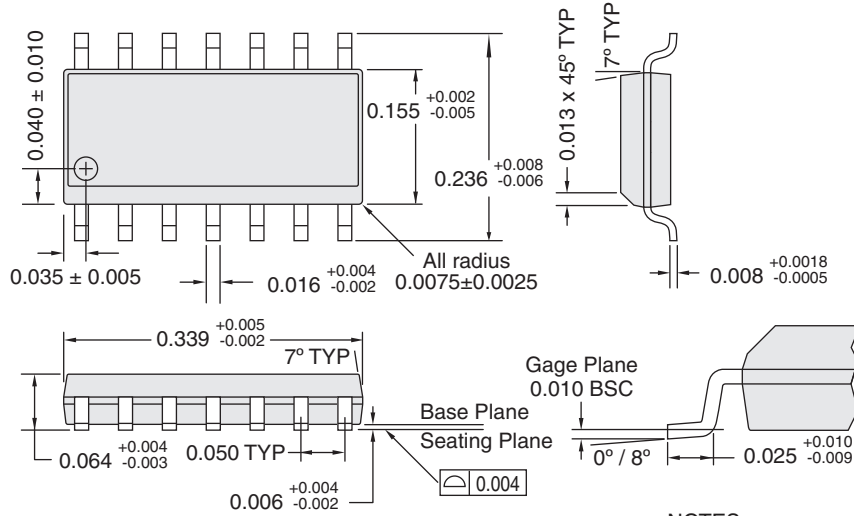
Recommended PCB Land Pattern
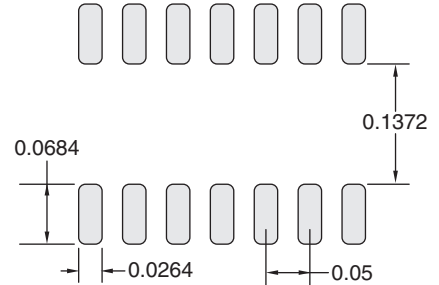
NOTES:
1. Controlling dimension: inches
2. Molded package dimensions do not include mold flash or protrusion. Mold flash or protrusion shall not exceed 6 mils per side.
3. Formed leads shall be planar with respect to one another within 4 mils referenced from the seating plane.
4. The bottom package lead side may be bigger than the top package lead side by 4 mils (2 mils per side). Bottom package dimension shall follow dimension stated in this drawing.
5. This drawing conforms to JEDEC REF. MS-012 Rev. E.

Important Notice

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at **https://www.littelfuse.com/disclaimer-electronics.**

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Gate Drivers *category:*

Click to view products by IXYS *manufacturer:*

Other Similar products are found below :

00053P0231 56956 57.404.7355.5 LT4936 57.904.0755.0 5882900001 00600P0005 00-9050-LRPP 00-9090-RDPP 5951900000 01-1003W-10/32-15 0131700000 00-2240 LTP70N06 LVP640 5J0-1000LG-SIL LY1D-2-5S-AC120 LY2-US-AC240 LY3-UA-DC24 00576P0020 00600P0010 LZN4-UA-DC12 LZNQ2M-US-DC5 LZNQ2-US-DC12 LZP40N10 00-8196-RDPP 00-8274-RDPP 00-8275-RDNP 00-8722-RDPP 00-8728-WHPP 00-8869-RDPP 00-9051-RDPP 00-9091-LRPP 00-9291-RDPP 0207100000 0207400000 01312 0134220000 60713816 M15730061 61161-90 61278-0020 6131-204-23149P 6131-205-17149P 6131-209-15149P 6131-218-17149P 6131-220-21149P 6131-260-2358P 6131-265-11149P CS1HCPU63